# 74LVC823A

9-bit D-type flip-flop with 5 V tolerant inputs/outputs; positive edge-trigger; 3-state

Rev. 4 — 8 April 2013

**Product data sheet** 

## 1. General description

The 74LVC823A is a 9-bit D-type flip-flop with common clock (pin CP), clock enable (pin CE), master reset (pin MR) and 3-state outputs (pins Qn) for bus-oriented applications. The 9 flip-flops stores the state of their individual D-inputs that meet the set-up and hold times requirements on the LOW to HIGH CP transition, provided pin CE is LOW. When pin CE is HIGH, the flip-flops hold their data. A LOW on pin MR resets all flip-flops. When pin OE is LOW, the contents of the 9 flip-flops are available at the outputs. When pin OE is HIGH, the outputs go to the high-impedance OFF-state. Operation of the OE input does not affect the state of the flip-flops.

Inputs can be driven from either 3.3 V or 5 V devices. When disabled, up to 5.5 V can be applied to the outputs. These features allow the use of these devices as translators in mixed 3.3 V and 5 V applications.

## 2. Features and benefits

- 5 V tolerant inputs/outputs for interfacing with 5 V logic
- Wide supply voltage range from 1.2 V to 3.6 V
- CMOS low power consumption
- Direct interface with TTL levels
- Flow-through pinout architecture
- 9-bit positive edge-triggered register
- Independent register and 3-state buffer operation
- Complies with JEDEC standard:
  - ◆ JESD8-7A (1.65 V to 1.95 V)
  - ◆ JESD8-5A (2.3 V to 2.7 V)
  - ◆ JESD8-C/JESD36 (2.7 V to 3.6 V)
- ESD protection:
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-B exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C.



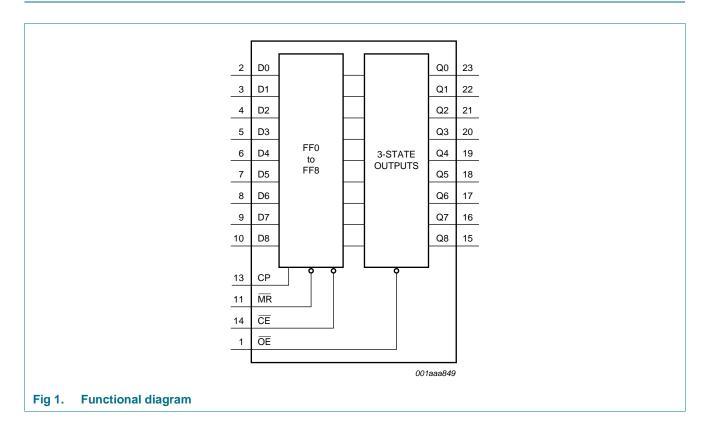
9-bit D-type flip-flop; 5 V tolerance; positive edge-trigger; 3-state

# 3. Ordering information

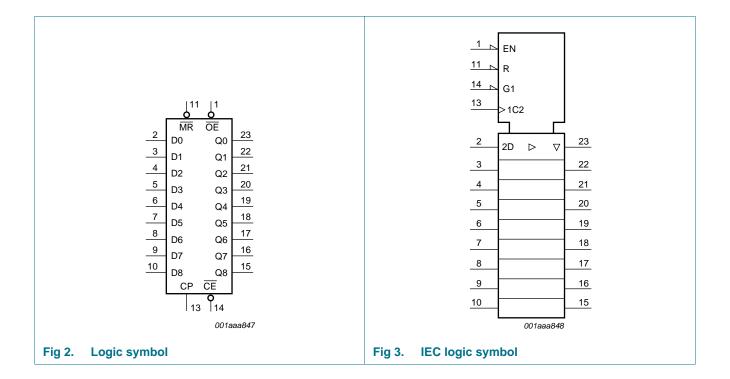
Table 1. Ordering information

Type number	Package	Package									
	Temperature range	Name	Description	Version							
74LVC823AD	–40 °C to +125 °C	SO24	plastic small outline package; 24 leads; body width 7.5 mm	SOT137-1							
74LVC823ADB	–40 °C to +125 °C	SSOP24	plastic shrink small outline package; 24 leads; body width 5.3 mm	SOT340-1							
74LVC823APW	–40 °C to +125 °C	TSSOP24	plastic thin shrink small outline package; 24 leads; body width 4.4 mm	SOT355-1							
74LVC823ABQ	–40 °C to +125 °C	DHVQFN24	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 24 terminals; body $3.5\times5.5\times0.85$ mm	SOT815-1							

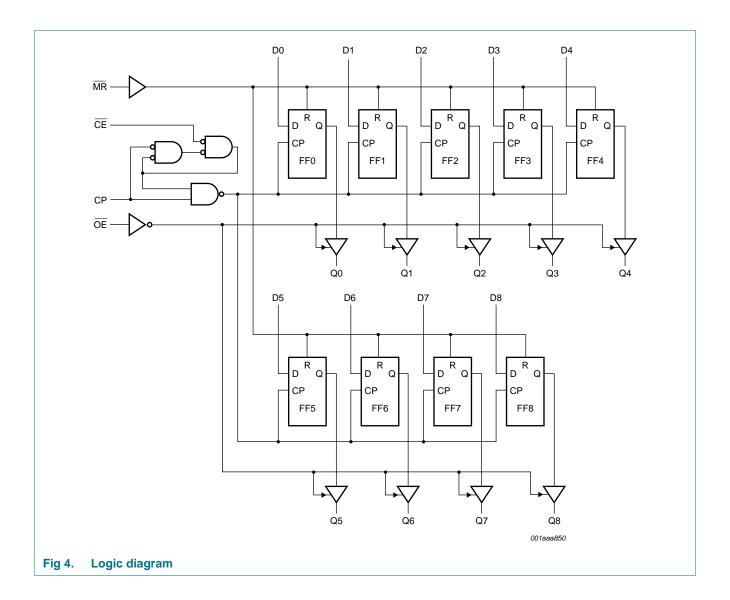
# 4. Functional diagram



9-bit D-type flip-flop; 5 V tolerance; positive edge-trigger; 3-state



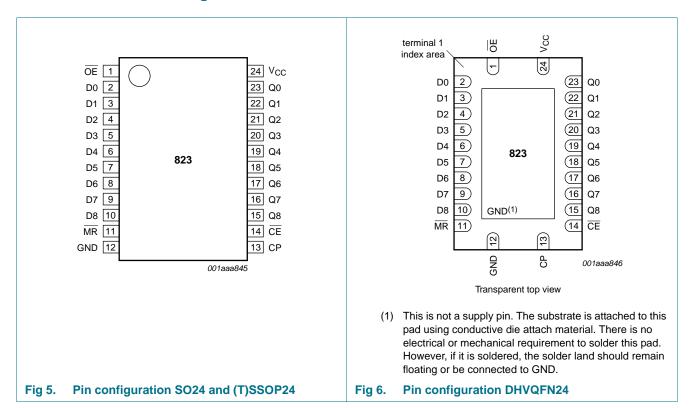
9-bit D-type flip-flop; 5 V tolerance; positive edge-trigger; 3-state



#### 9-bit D-type flip-flop; 5 V tolerance; positive edge-trigger; 3-state

## 5. Pinning information

#### 5.1 Pinning



#### 5.2 Pin description

Table 2. Pin description

Pin	Name	Description
ŌĒ	1	output enable input (active LOW)
MR	11	master reset input (active LOW)
D[0:8]	2, 3, 4, 5, 6, 7, 8, 9, 10	data input
Q[0:8]	23, 22, 21, 20, 19, 18, 17, 16, 15	3-state flip-flop output
СР	13	clock input (LOW to HIGH; edge-triggered)
CE	14	clock enable input (active LOW)
GND	12	ground (0 V)
$V_{CC}$	24	supply voltage

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## 6. Functional description

Table 3. Function table [1]

Operating mode	Input		Internal	Output			
	OE	MR	CE	СР	Dn	flip-flop	Qn
Clear	L	L	Χ	X	Χ	L	L
Load and read register	L	Н	L	<b>↑</b>	1	L	L
	L	Н	L	<b>↑</b>	h	Н	Н
Load register and	Н	Н	L	<b>↑</b>	I	L	Z
disable outputs	Н	Н	L	<b>↑</b>	h	Н	Z
Hold	L	Н	Н	NC	Χ	NC	NC

<sup>[1]</sup> H = HIGH voltage level

h = HIGH voltage level one set-up time prior to the LOW to HIGH CP transition

I = LOW voltage level one set-up time prior to the LOW to HIGH CP transition

NC = no change

# 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CC}$	supply voltage			-0.5	+6.5	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+6.5	V
I <sub>OK</sub>	output clamping current	$V_O > V_{CC}$ or $V_O < 0 V$		-	±50	mA
Vo	output voltage	HIGH or LOW state	<u>[2]</u>	-0.5	$V_{CC} + 0.5$	V
		3-state	<u>[2]</u>	-0.5	+6.5	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$		-	±50	mA
$I_{CC}$	supply current			-	100	mA
$I_{GND}$	ground current			-100	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$	[3]	-	500	mW

<sup>[1]</sup> The minimum input voltage ratings may be exceeded if the input current ratings are observed.

L = LOW voltage level

Z = high-impedance OFF-state

<sup>↑ =</sup> LOW to HIGH level transition

X = don't care

<sup>[2]</sup> The output voltage ratings may be exceeded if the output current ratings are observed.

<sup>[3]</sup> For SO24 packages:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C.

For SSOP24 and TSSOP24 packages: Ptot derates linearly with 5.5 mW/K above 60  $^{\circ}\text{C}.$ 

For DHVQFN24 packages: Ptot derates linearly with 4.5 mW/K above 60 °C.

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# 8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CC}$	supply voltage		1.65	-	3.6	V
		functional	1.2	-	-	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	HIGH or LOW state	0	-	$V_{CC}$	V
		3-state	0	-	5.5	V
T <sub>amb</sub>	ambient temperature	in free air	-40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall	$V_{CC} = 1.65 \text{ V to } 2.7 \text{ V}$	0	-	20	ns/V
	rate	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	0	-	10	ns/V

## 9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	85 °C	-40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 1.2 V	1.08	-	-	1.08	-	V
	input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65 \times V_{CC}$	-	-	$0.65 \times V_{CC}$	-	٧
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
$V_{IL}$	LOW-level	V <sub>CC</sub> = 1.2 V	-	-	0.12	-	0.12	V
	input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	$0.35 \times V_{CC}$	1.08 0.65 × V <sub>CC</sub> 1.7 2.0	$0.35 \times V_{CC}$	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
V <sub>OH</sub> HIGH-level		$V_I = V_{IH}$ or $V_{IL}$						
	output voltage	$I_O = -100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 3.6 \text{ V}$	V <sub>CC</sub> - 0.2	-	-	$V_{CC}-0.3$	-	V
		$I_O = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.2	-	-	1.05	-	V
		$I_{O} = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.8	-	-	1.65	-	V
		$I_{O} = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.2	-	-	2.05	-	V
		$I_{O} = -18 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.4	-	-	2.25	-	V
		$I_{O} = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.2	-	-	2.0	-	V
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$					Max 0.12 0.35 × V <sub>CC</sub> 0.7 0.8	
	output voltage	$I_O = 100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 3.6 \text{ V}$	-	-	0.2	-	0.3	V
		$I_O = 4 \text{ mA}$ ; $V_{CC} = 1.65 \text{ V}$	-	-	0.45	-	0.65	V
		$I_O = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.6	-	0.8	V
		$I_O = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	-	0.4	-	0.6	V
		$I_O = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.55	-	0.8	V
I <sub>I</sub>	input leakage current	$V_{CC}$ = 3.6 V; $V_I$ = 5.5 V or GND	-	±0.1	±5	-	±20	μΑ

9-bit D-type flip-flop; 5 V tolerance; positive edge-trigger; 3-state

Table 6. Static characteristics ...continued

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +85	°C	–40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
I <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 3.6$ V; $V_O = 5.5$ V or GND;	-	0.1	±5	-	±20	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{CC} = 0 \text{ V}$ ; $V_I \text{ or } V_O = 5.5 \text{ V}$	-	0.1	±10	-	±20	μΑ
I <sub>CC</sub>	supply current	$V_{CC}$ = 3.6 V; $V_{I}$ = $V_{CC}$ or GND; $I_{O}$ = 0 A	-	0.1	10	-	40	μА
$\Delta I_{CC}$	additional supply current	per input pin; $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V};$ $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}$	-	5	500	-	5000	μΑ
C <sub>I</sub>	input capacitance	$V_{CC} = 0 \text{ V to } 3.6 \text{ V};$ $V_I = \text{GND to } V_{CC}$	-	5.0	-	-	-	pF

<sup>[1]</sup> All typical values are measured at  $V_{CC}$  = 3.3 V (unless stated otherwise) and  $T_{amb}$  = 25 °C.

# 10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 11.

Symbol Parameter		Conditions	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +85  ^{\circ}\text{C}$			-40 °C to	Unit		
				Min	Typ[1]	Max	Min	Max	
t <sub>pd</sub>	propagation	CP to Qn; see Figure 7	[2]						
	delay	V <sub>CC</sub> = 1.2 V		-	20	-	-	-	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		2.4	8.4	18.7	2.4	21.5	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.7	4.4	9.6	1.7	11.1	ns
		V <sub>CC</sub> = 2.7 V		1.5	4.1	8.9	1.5	11.5	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.5	3.7	8.0	1.5	10.0	ns
t <sub>PHL</sub> HIGH to LOW	MR to Qn; see Figure 9								
	propagation delay	V <sub>CC</sub> = 1.2 V		-	15	-	-	-	ns
	delay	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		2.1	9.5	21.4	2.1	24.7	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.5	4.9	10.5	1.5	12.1	ns
		V <sub>CC</sub> = 2.7 V		1.5	4.7	8.8	1.5	11.0	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.5	4.1	7.9	1.5	10.0	ns
t <sub>en</sub>	enable time	OE to Qn; see Figure 10	[2]						
		V <sub>CC</sub> = 1.2 V		-	18	-	-	-	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		1.7	7.4	16.5	1.7	19.0	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.5	4.2	9.1	1.5	10.5	ns
		$V_{CC} = 2.7 \text{ V}$		1.5	4.3	8.3	1.5	10.5	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.5	3.4	7.2	1.5	9.0	ns

## 9-bit D-type flip-flop; 5 V tolerance; positive edge-trigger; 3-state

 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 11.

Symbol	Parameter	Conditions	T <sub>amb</sub> =	–40 °C to	+85 °C	–40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
t <sub>dis</sub>	disable time	OE to Qn; see Figure 10	[2]					
		V <sub>CC</sub> = 1.2 V	-	8.0	-	-	-	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	2.3	4.2	10.0	2.3	11.5	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.0	2.3	5.6	1.0	6.5	ns
		V <sub>CC</sub> = 2.7 V	1.5	3.2	7.1	1.5	9.0	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	1.5	2.9	6.0	1.5	7.5	ns
t <sub>W</sub>	pulse width	clock HIGH or LOW; see Figure 7						
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	5.0	-	-	5.0	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	4.0	-	-	4.0	-	ns
		V <sub>CC</sub> = 2.7 V	3.3	-	-	3.3	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	3.3	1.7	-	3.3	-	ns
		master reset HIGH or LOW; see <u>Figure 9</u>						
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	5.0	-	-	5.0	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	4.0	-	-	4.0	-	ns
		V <sub>CC</sub> = 2.7 V	3.3	-	-	3.3	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	3.3	1.7	-	3.3	-	ns
t <sub>su</sub>	set-up time	Dn to CP; see Figure 8						
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	3.0	-	-	3.0	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.0	-	-	2.0	-	ns
		V <sub>CC</sub> = 2.7 V	1.0	-	-	1.0	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	+1.8	-0.8	-	+1.8	-	ns
		CE to CP; see Figure 8						
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	3.0	-	-	3.0	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.0	-	-	2.0	-	ns
		V <sub>CC</sub> = 2.7 V	1.8	-	-	1.8	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	1.3	0.0	-	1.3	-	ns
t <sub>rec</sub>	recovery time	MR; see Figure 9						
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	3.0	-	-	3.0	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.5	-	-	2.5	-	ns
		$V_{CC} = 2.7 \text{ V}$	2.0	-	-	2.0	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	+1.0	-0.5	-	+1.0	-	ns

## 9-bit D-type flip-flop; 5 V tolerance; positive edge-trigger; 3-state

 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 11.

Symbol	Parameter	Conditions		T <sub>amb</sub> =	–40 °C to	+85 °C	–40 °C to	+125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t <sub>h</sub>	hold time	Dn to CP; see Figure 8							
		V <sub>CC</sub> = 1.65 V to 1.95 V		3.0	-	-	3.0	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2.5	-	-	2.5	-	ns
		V <sub>CC</sub> = 2.7 V		2.0	-	-	2.0	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		2.0	0.8	-	2.0	-	ns
		CE to CP; see Figure 8							
		V <sub>CC</sub> = 1.65 V to 1.95 V		3.0	-	-	3.0	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2.0	-	-	2.0	-	ns
		V <sub>CC</sub> = 2.7 V		1.3	-	-	1.3	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.3	0.0	-	1.3	-	ns
$f_{\text{max}}$	maximum	see Figure 7							
	frequency	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		100	-	-	80	-	MHz
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		125	-	-	100	-	MHz
		$V_{CC} = 2.7 \text{ V}$		150	-	-	120	-	MHz
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		150	200	-	120	-	MHz
t <sub>sk(o)</sub>	output skew time	$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	<u>[3]</u>	-	-	1.0	-	1.5	ns
$C_{PD}$	power	per input; $V_I = GND$ to $V_{CC}$	<u>[4]</u>						
	dissipation	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		-	12.4	-	-	-	pF
	capacitance	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-	14.5	-	-	-	pF
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		-	16.4	-	-	-	pF

<sup>[1]</sup> Typical values are measured at  $T_{amb}$  = 25 °C and  $V_{CC}$  = 1.2 V, 1.8 V, 2.5 V, 2.7 V and 3.3 V respectively.

[3] Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

[4]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

 $f_i$  = input frequency in MHz;  $f_o$  = output frequency in MHz

 $C_L$  = output load capacitance in pF

V<sub>CC</sub> = supply voltage in Volts

N = number of inputs switching

 $\Sigma (C_L \times V_{CC}{}^2 \times f_o)$  = sum of the outputs

 $<sup>\</sup>begin{array}{ll} \text{[2]} & t_{\text{pd}} \text{ is the same as } t_{\text{PLH}} \text{ and } t_{\text{PHL}}. \\ & t_{\text{en}} \text{ is the same as } t_{\text{PZL}} \text{ and } t_{\text{PZH}}. \\ & t_{\text{dis}} \text{ is the same as } t_{\text{PLZ}} \text{ and } t_{\text{PHZ}}. \end{array}$ 

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## 11. Waveforms

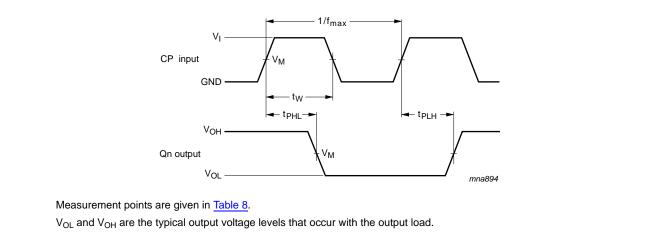
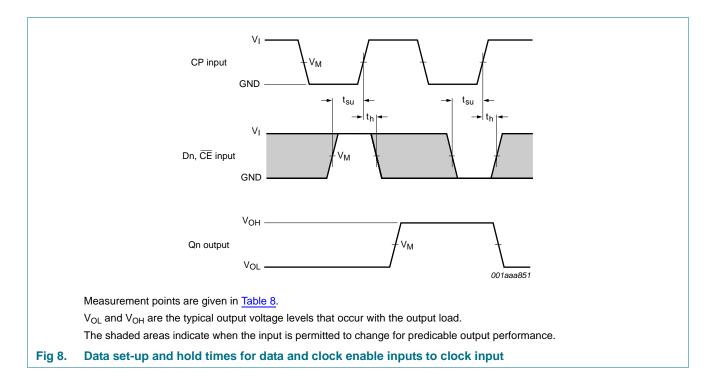


Fig 7. Clock to output propagation delays, clock pulse width, and maximum frequency



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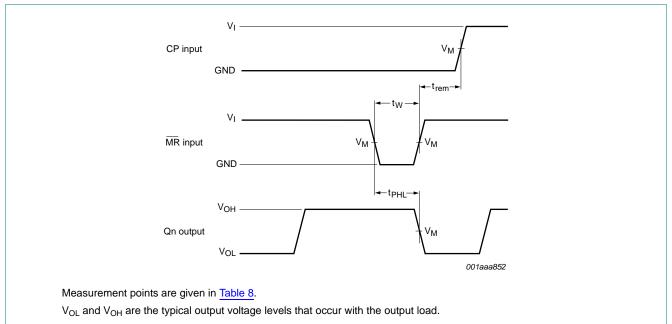
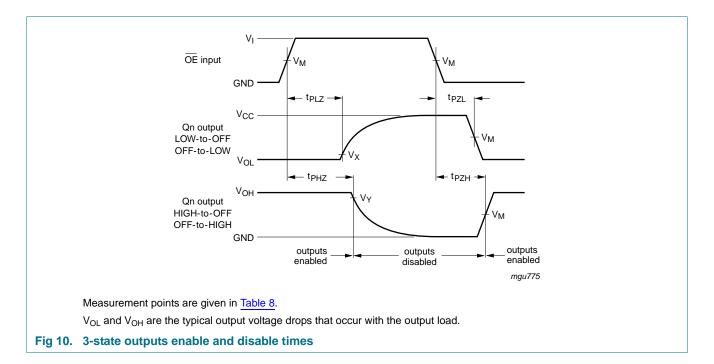


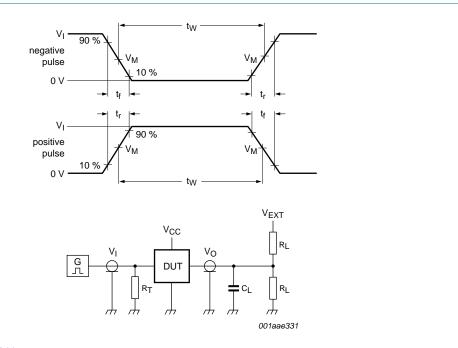
Fig 9. Master reset pulse width, master reset to clock removal time and master reset to output propagation delay



## 9-bit D-type flip-flop; 5 V tolerance; positive edge-trigger; 3-state

Table 8. Measurement points

Supply voltage	Input		Output		
V <sub>CC</sub>	VI	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>
1.2 V	$V_{CC}$	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V <sub>OL</sub> + 0.15 V	$V_{OH}-0.15\ V$
1.65 V to 1.95 V	$V_{CC}$	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> – 0.15 V
2.3 V to 2.7 V	$V_{CC}$	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> – 0.15 V
2.7 V	2.7 V	1.5 V	1.5 V	V <sub>OL</sub> + 0.3 V	$V_{OH} - 0.3 V$
3.0 V to 3.6 V	2.7 V	1.5 V	1.5 V	V <sub>OL</sub> + 0.3 V	$V_{OH} - 0.3 V$



Test data is given in Table 9.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

 $\ensuremath{C_L}$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

V<sub>EXT</sub> = External voltage for measuring switching times.

Fig 11. Load circuitry for switching times

Table 9. Test data

Supply voltage	Input	Input		Load		V <sub>EXT</sub>		
	V <sub>I</sub>	t <sub>r</sub> , t <sub>f</sub>	CL	R <sub>L</sub>	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PLZ</sub> , t <sub>PZL</sub>	t <sub>PHZ</sub> , t <sub>PZH</sub>	
1.2 V	$V_{CC}$	≤ 2 ns	30 pF	1 kΩ	open	$2\times V_{CC}$	GND	
1.65 V to 1.95 V	$V_{CC}$	≤ 2 ns	30 pF	1 kΩ	open	$2\times V_{CC}$	GND	
2.3 V to 2.7 V	$V_{CC}$	≤ 2 ns	30 pF	$500\Omega$	open	$2\times V_{CC}$	GND	
2.7 V	2.7 V	≤ 2.5 ns	50 pF	$500 \Omega$	open	$2\times V_{CC}$	GND	
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	$500 \Omega$	open	$2\times V_{CC}$	GND	

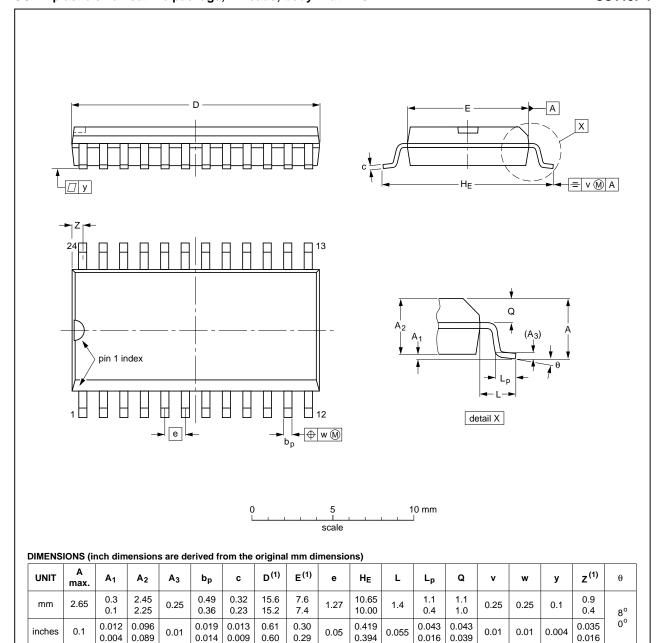
74LVC823A

## 9-bit D-type flip-flop; 5 V tolerance; positive edge-trigger; 3-state

## 12. Package outline

SO24: plastic small outline package; 24 leads; body width 7.5 mm

SOT137-1



#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT137-1	075E05	MS-013			<del>99-12-27</del> 03-02-19	

Fig 12. Package outline SOT137-1 (SO24)

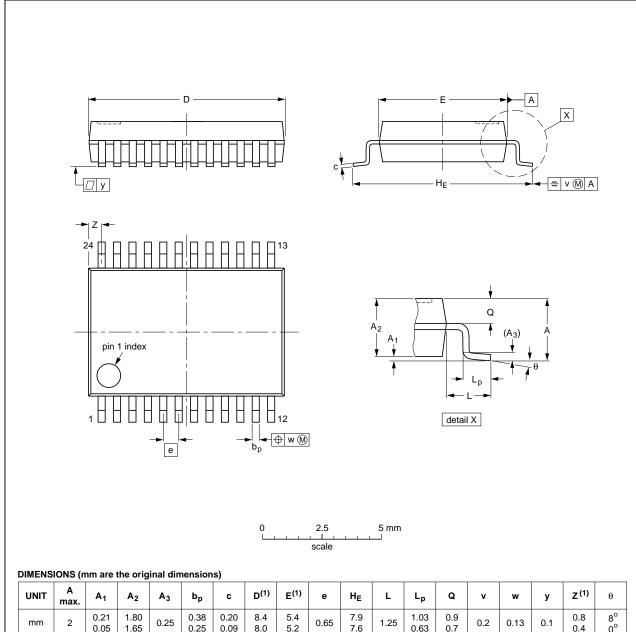
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## 9-bit D-type flip-flop; 5 V tolerance; positive edge-trigger; 3-state

SSOP24: plastic shrink small outline package; 24 leads; body width 5.3 mm

SOT340-1



UNI	T A	. A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mn	1 2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	8.4 8.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.8 0.4	8° 0°

#### Note

1. Plastic or metal protrusions of 0.2 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT340-1		MO-150	-		<del>99-12-27</del> 03-02-19

Fig 13. Package outline SOT340-1 (SSOP24)

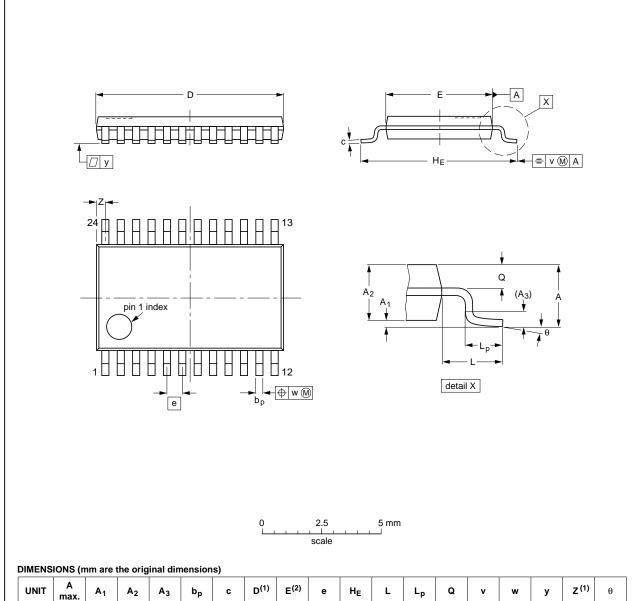
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## 9-bit D-type flip-flop; 5 V tolerance; positive edge-trigger; 3-state

TSSOP24: plastic thin shrink small outline package; 24 leads; body width 4.4 mm

SOT355-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	7.9 7.7	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT355-1		MO-153			<del>-99-12-27</del> 03-02-19	

Fig 14. Package outline SOT355-1 (TSSOP24)

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#### 9-bit D-type flip-flop; 5 V tolerance; positive edge-trigger; 3-state

# DHVQFN24: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 24 terminals; body $3.5 \times 5.5 \times 0.85$ mm

SOT815-1

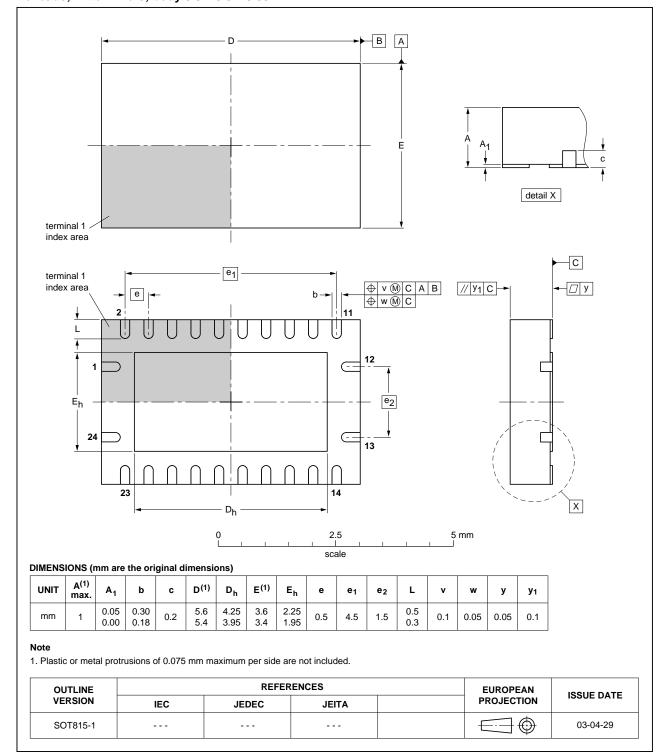


Fig 15. Package outline SOT815-1 (DHVQFN24)

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9-bit D-type flip-flop; 5 V tolerance; positive edge-trigger; 3-state

## 13. Abbreviations

#### Table 10. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

# 14. Revision history

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC823A v.4	20130408	Product data sheet	-	74LVC823A v.3
Modifications:	<ul> <li>Features corre</li> </ul>	ected (errata).		
74LVC823A v.3	20130327	Product data sheet	-	74LVC823A v.2
Modifications:	<ul> <li>The format of of NXP Semice</li> </ul>	this data sheet has been reconductors.	lesigned to comply with	n the new identity guidelines
	<ul> <li>Legal texts have</li> </ul>	ve been adapted to the new	company name where	appropriate.
	• Table 4, Table	5, Table 6, Table 7, Table 8	and <u>Table 9</u> : values add	ded for lower voltage ranges.
74LVC823A v.2	20040510	Product specification	-	74LVC823A v.1
74LVC823A v.1	19980924	Product specification	-	-

#### 9-bit D-type flip-flop; 5 V tolerance; positive edge-trigger; 3-state

## 15. Legal information

#### 15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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#### 9-bit D-type flip-flop; 5 V tolerance; positive edge-trigger; 3-state

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